## **SPICE Device Model SQS423EN**



Vishay Siliconix

## P-Channel 30 V (D-S) MOSFET

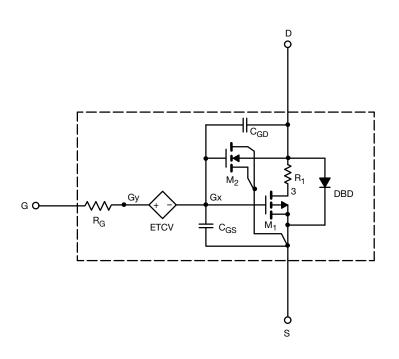
### DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### SUBCIRCUIT MODEL SCHEMATIC

### **CHARACTERISTICS**

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics



#### Note

 This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -250 \ \mu A$	2.4	-	V
Drain-Source On-State Resistance <sup>a</sup>	Б	V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 12 A	0.014	0.018	Ω
	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 9 A	0.043	0.030	
Forward Transconductance <sup>a</sup>	<b>g</b> <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 12 A	12	12	S
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = - 8.8 A	- 0.91	- 0.80	V
Dynamic <sup>b</sup>		·			
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = - 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz	1580	1575	pF
Output Capacitance	C <sub>oss</sub>		347	335	
Reverse Transfer Capacitance	C <sub>rss</sub>		247	240	
Total Gate Charge	Qg	$V_{DS}$ = - 15 V, $V_{GS}$ = - 10 V, $I_D$ = - 10.5 A	32	33	nC
Gate-Source Charge	Q <sub>gs</sub>		5.9	5.9	
Gate-Drain Charge	Q <sub>gd</sub>		9.2	9.2	

Notes

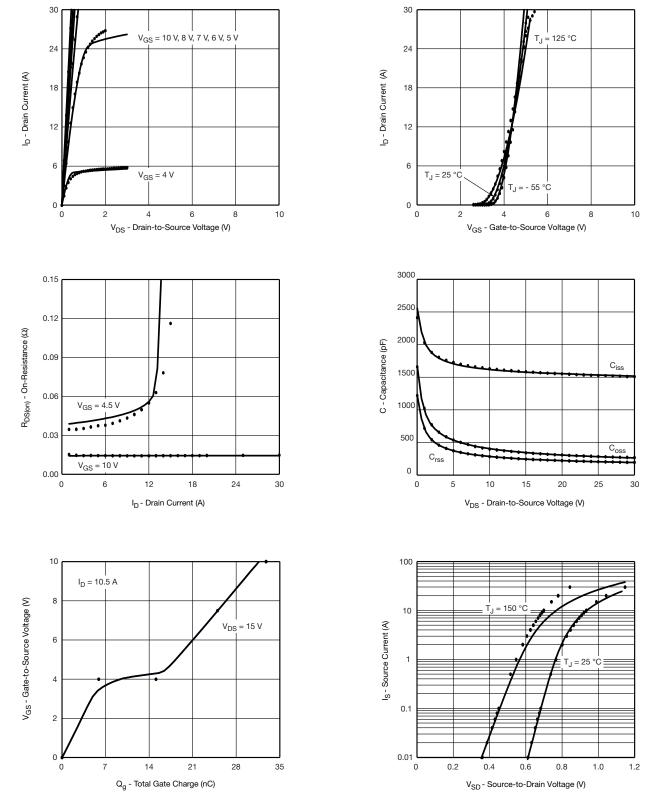
a. Pulse test; pulse width  $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%.$ 

b. Guaranteed by design, not subject to production testing.



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### COMPARISON OF MODEL WITH MEASURED DATA (T<sub>J</sub> = 25 °C, unless otherwise noted)



#### Note

• Dots and squares represent measured data.

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